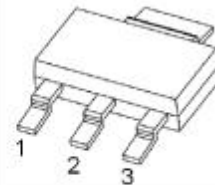


FEATURES

- For AF driver and output stages
- High collector current
- Low collector-emitter saturation voltage

SOT-223


1. BASE
2. COLLECTOR
3. EMITTER

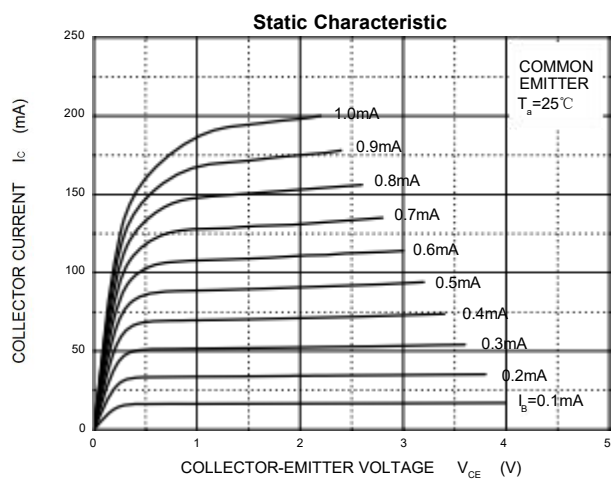
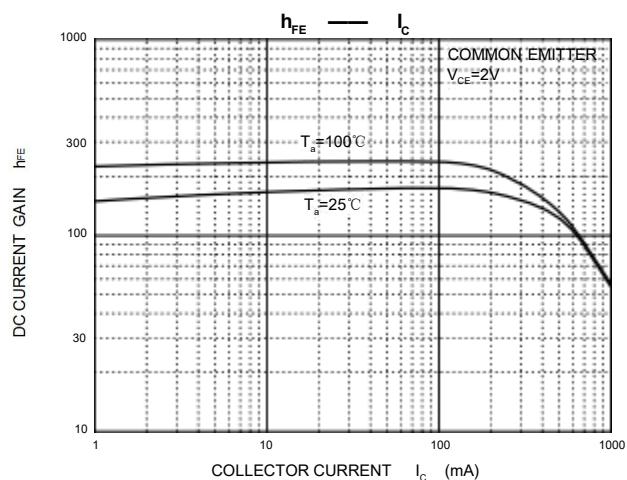
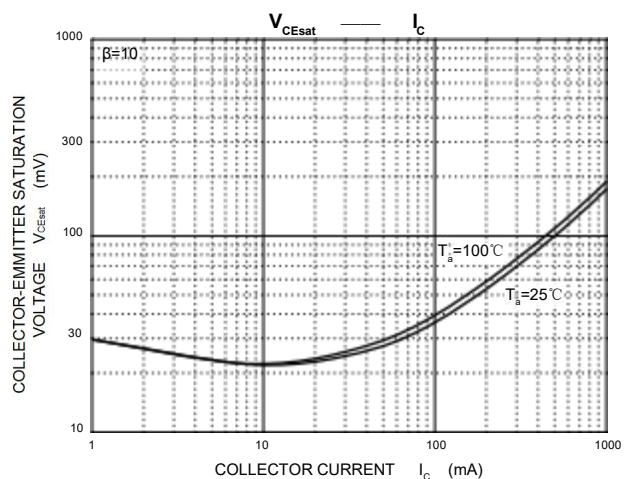
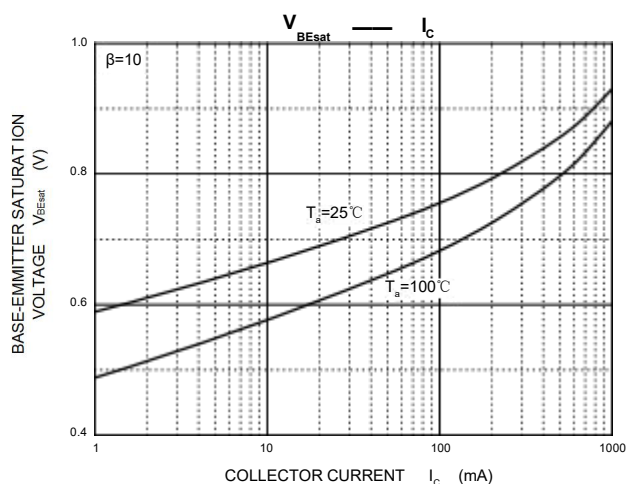
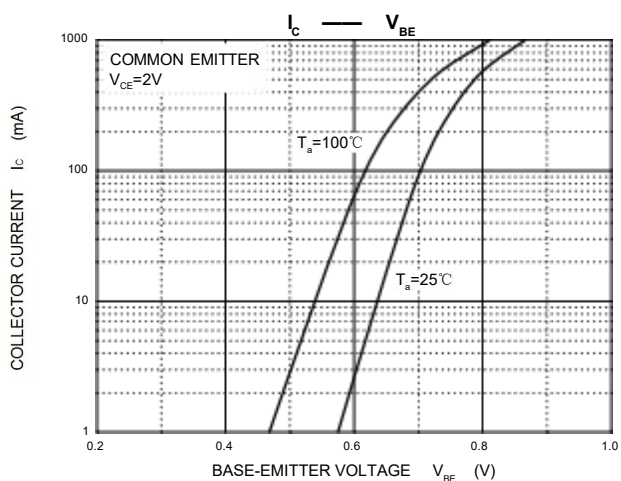
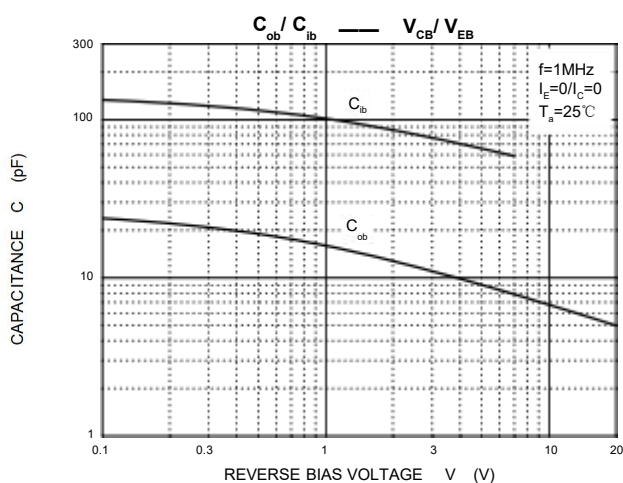
MAXIMUM RATINGS (T_a=25°C unless otherwise noted)

Symbol	Parameter	BCP56-16-CN	Unit
V _{CBO}	Collector-Base Voltage	100	V
V _{CEO}	Collector-Emitter Voltage	80	V
V _{EBO}	Emitter-Base Voltage	5	V
I _C	Collector Current -Continuous	1	A
I _{CM}	Peak Pulse Collector Current	2	A
I _B	Base Current-Continuous	100	mA
I _{BM}	Peak Pulse Base Current	200	mA
P _C	Collector Power Dissipation	1.5	W
T _J , T _{stg}	Operation Junction and Storage Temperature Range	-55~+150	°C
R _{θJA}	Thermal Resistance Junction to Ambient	83.3	°C/W

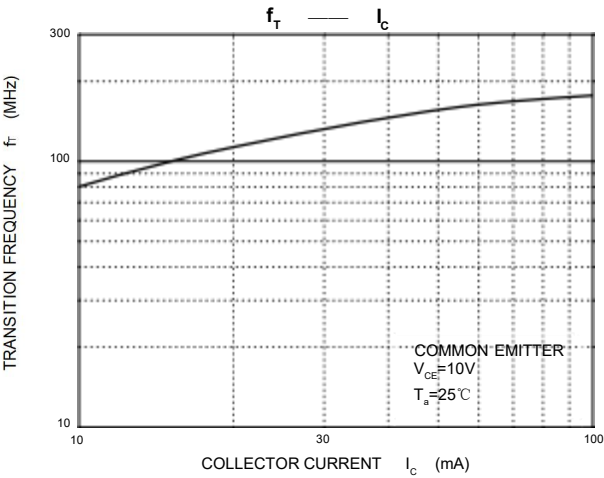
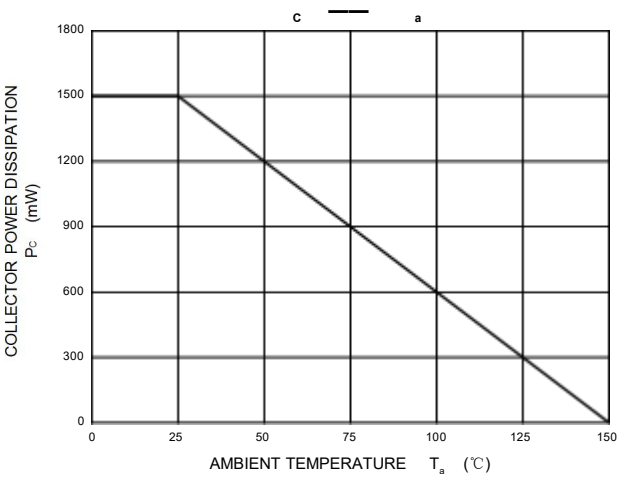
ELECTRICAL CHARACTERISTICS (T_a=25°C unless otherwise specified)

Parameter	Symbol	Test conditions	Min	Max	Unit
Collector-base breakdown voltage	V _{(BR)CBO}	I _C = 0.1mA, I _E =0	100		V
Collector-emitter breakdown voltage	V _{(BR)CEO}	I _C = 10mA, I _B =0	80		V
Base-emitter breakdown voltage	V _{(BR)EBO}	I _E = 10μA, I _C =0	5		V
Collector cut-off current	I _{CBO}	V _{CB} = 30 V, I _E =0		100	nA
DC current gain	h _{FE(1)}	V _{CE} = 2V, I _C =5mA	25		
	h _{FE(2)}	V _{CE} = 2V, I _C =150mA	63	250	
	h _{FE(3)}	V _{CE} = 2V, I _C =500mA	25		
Collector-emitter saturation voltage	V _{CE(sat)}	I _C =500mA, I _B =50mA		0.5	V
Base-emitter voltage	V _{BE}	V _{CE} =2V, I _C =500mA		1	V
Transition frequency	f _T	V _{CE} =10V, I _C =50mA, f=100MHz	100		MHz

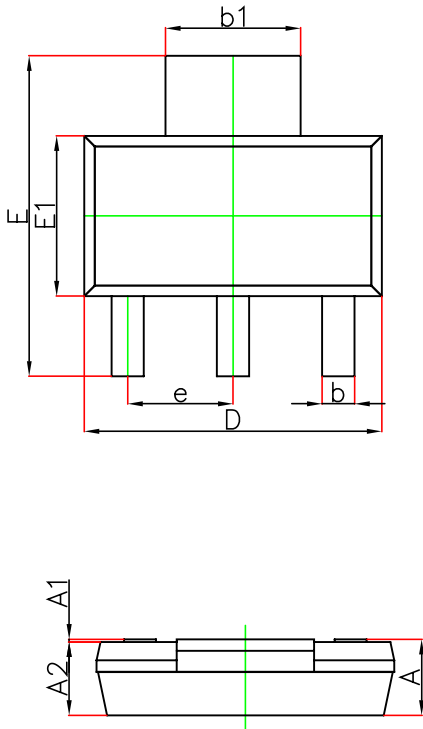
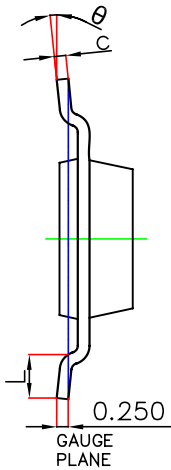
Typical Characteristics



P T

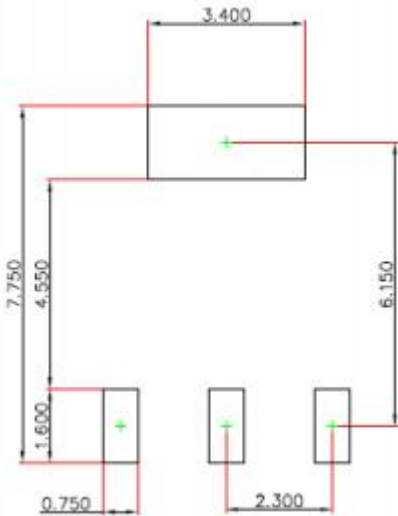


SOT-223 Package Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	—	1.800	—	0.071
A1	0.020	0.100	0.001	0.004
A2	1.500	1.700	0.059	0.067
b	0.660	0.840	0.026	0.033
b1	2.900	3.100	0.114	0.122
c	0.230	0.350	0.009	0.014
D	6.300	6.700	0.248	0.264
E	6.700	7.300	0.264	0.287
E1	3.300	3.700	0.130	0.146
e	2.300(BSC)		0.091(BSC)	
L	0.750	—	0.030	—
θ	0°	10°	0°	10°

SOT-223 Suggested Pad Layout



Note:

- controlling dimension:in millimeters.
- General tolerance:±0.050mm.
- The pad layout is for reference purposes only.

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